2SC4662

Silicon NPN Triple Diffused Planar Transistor (High Voltage and High Speed Switching Transistor)

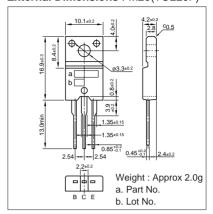
Application: Switching Regulator and General Purpose

■Absolute maximum ratings (Ta=25°C)

Symbol	Ratings	Unit
Vсво	500	V
VCEO	400	V
VEBO	10	V
Ic	5(Pulse10)	А
Ів	2	А
Pc	30(Tc=25°C)	W
Tj	150	°C
Tstg	-55 to +150	°C

Electrical Ci	iaracteristics	(1a=25 C)		
Symbol	Conditions	Ratings	Unit	
Ісво	Vcb=500V	100max	μΑ	
IEBO	VEB=10V	100max	μΑ	
V(BR)CEO	Ic=25mA	400min	V	
hfe	Vce=4V, Ic=1.5A	10 to 30		
Vce(sat)	Ic=1.5A, IB=0.3A	0.5max	V	
VBE(sat)	Ic=1.5A, IB=0.3A	1.3max	V	
fr	Vce=12V, Ie=-0.3A	20typ	MHz	
Сов	VcB=10V, f=1MHz	30typ	pF	

External Dimensions FM20(TO220F)

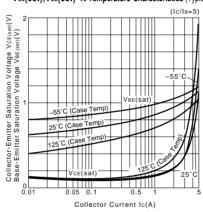


■Typical Switching Characteristics (Common Emitter)

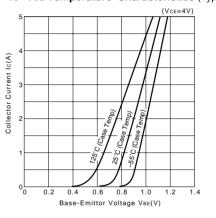
Vcc (V)	RL (Ω)	Ic (A)	V _{BB1} (V)	VBB2 (V)	I _{B1} (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
200	133	1.5	10	-5	0.15	-0.3	1max	2.5max	0.5max

Ic-VcE Characteristics (Typical)

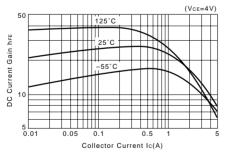
VcE(sat), VBE(sat)-Ic Temperature Characteristics (Typical)



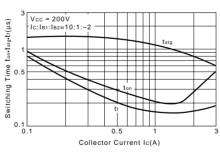
Ic-VBE Temperature Characteristics (Typical)



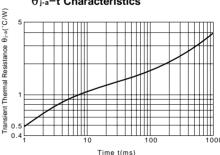
hfe-Ic Temperature Characteristics (Typical)



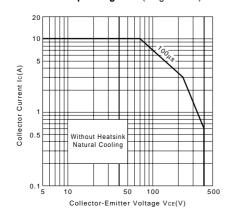
ton • tstg • tf-Ic Characteristics (Typical)



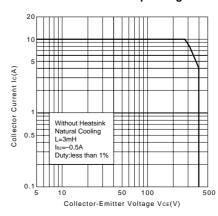
 θ_{j-a} -t Characteristics



Safe Operating Area (Single Pulse)



Reverse Bias Safe Operating Area



Pc-Ta Derating

